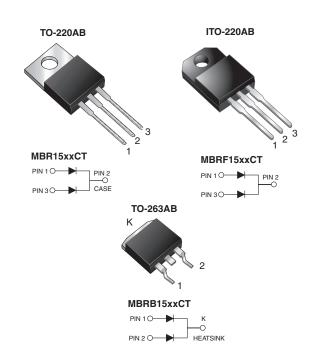


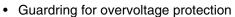
Vishay General Semiconductor

Dual Common-Cathode Schottky Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)}	7.5 A x 2				
V_{RRM}	35 V to 60 V				
I _{FSM}	150 A				
V_{F}	0.57 V, 0.65 V				
T _J max.	150 °C				

FEATURES





- Lower power losses, high efficiency
- Low forward voltage drop
- _
- High forward surge capability
- COMPLIA
- · High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER		MBR1535CT	MBR1545CT	MBR1550CT	MBR1560CT	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	50	60	٧	
Working peak reverse voltage		35	45	50	60	V	
Maximum DC blocking voltage		35	45	50	60	V	
Maximum average forward rectified total device current at $T_C = 105$ °C per diode	I _{F(AV)}	15 7.5			Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150			Α		
Peak repetitive reverse surge current per diode at $t_p = 2.0~\mu s, 1~kHz$	I _{RRM}	I _{RRM} 1.0 0.5		.5	Α		
Voltage rate of change (rated V _R)	dV/dt	10 000				V/µs	
Operating junction temperature range	TJ	- 65 to + 150			°C		

MBR(F,B)1535CT thru MBR(F,B)1560CT

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MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL MBR1535CT MBR1545CT MBR1550CT MBR1560CT					UNIT
Storage temperature range	T _{STG}	- 65 to + 175			°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			٧	

ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS SYMBOL MBR1535CT MBR1545CT		MBR1550CT	MBR1560CT	UNIT			
Maximum instantaneous forward voltage per diode ⁽¹⁾	$I_F = 7.5 \text{ A}$ $I_F = 7.5 \text{ A}$ $I_F = 15 \text{ A}$ $I_F = 15 \text{ A}$	$T_{C} = 25 ^{\circ}\text{C}$ $T_{C} = 125 ^{\circ}\text{C}$ $T_{C} = 25 ^{\circ}\text{C}$ $T_{C} = 125 ^{\circ}\text{C}$	V _F		- 57 84 72	_	75 65 -	>
Maximum instantaneous reverse current at rated DC blocking voltage per diode (1)		T _C = 25 °C T _C = 125 °C	I _R	0.1 15			.0	mA

Note:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER SYMBOL MBR MBRF MBRB					UNIT	
Maximum thermal resistance per diode	$R_{ hetaJA} \ R_{ hetaJC}$	60 3.0	- 5.0	60 3.0	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR1545CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF1545CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB1545CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB1545CT-E3/81	1.35	81	800/reel	Tape reel		
TO-220AB	MBR1545CTHE3/45 (1)	1.85	45	50/tube	Tube		
ITO-220AB	MBRF1545CTHE3/45 (1)	1.99	45	50/tube	Tube		
TO-263AB	MBRB1545CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB1545CTHE3/81 (1)	1.35	81	800/reel	Tape reel		

Note:

(1) Automotive grade AEC Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

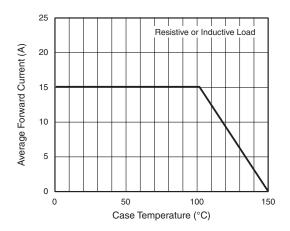


Figure 1. Forward Current Derating Curve

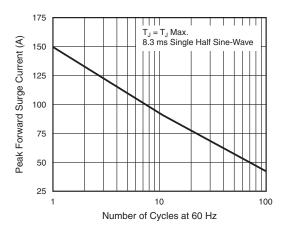


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

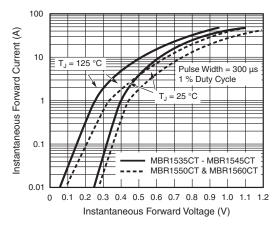


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

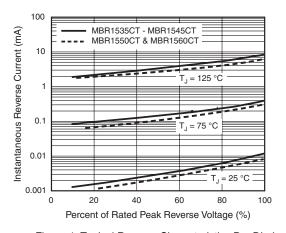


Figure 4. Typical Reverse Characteristics Per Diode

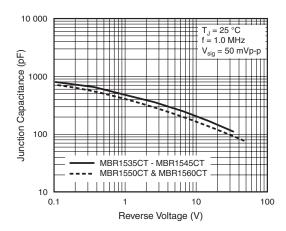


Figure 5. Typical Junction Capacitance Per Diode

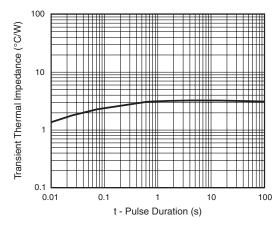


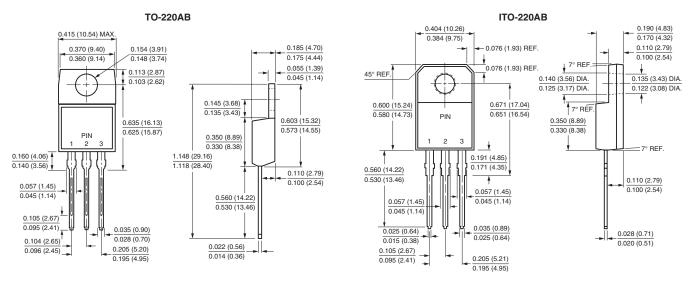
Figure 6. Typical Transient Thermal Impedance Per Diode

MBR(F,B)1535CT thru MBR(F,B)1560CT

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-263AB 0.411 (10.45) 0.190 (4.83) Mounting Pad Layout 0.380 (9.65) 0.055 (1.40) 0.160 (4.06) 0.245 (6.22) 0.045 (1.14) 0.42 (10.66) MIN MIN. 0.055 (1.40) 0.33 (8.38) MIN. 0.360 (9.14) 0.047 (1.19) 0.624 (15.85) 0.591 (15.00) 0.670 (17.02) - 0 to 0.01 (0 to 0.254) 0.591 (15.00) 0.110 (2.79) 0.090 (2.29) 0.021 (0.53) 0.037 (0.940) 0.15 (3.81) MIN. 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.08 (2.032) MIN. 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95) 0.105 (2.67) 0.095 (2.41)





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Revision: 11-Mar-11